DESCRIPTION

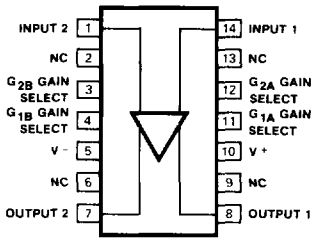
The 733 is a monolithic differential input, differential output, wideband video amplifier. It offers fixed gains of 10,100 or 400 without external components, and adjustable gains from 10 to 400 by the use of an external resistor. No external frequency compensation components are required for any gain option. Gain stability, wide bandwidth and low phase distortion are obtained through use of the classic series-shunt feedback from the emitter follower outputs to the inputs of the second stage. The emitter follower outputs provide low output impedance, and enable the device to drive capacitive loads. The 733 is intended for use as a high performance video and pulse amplifier in communications, magnetic memories, display and video recorder systems.

FEATURES

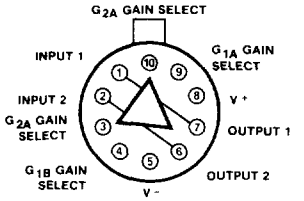
- **120MHz bandwidth**
- **250kΩ input resistance**
- **Selectable gains of 10,100 and 400**
- **No frequency compensation required**
- **Mil std 883A,B,C available**

PIN CONFIGURATION

F,N PACKAGE

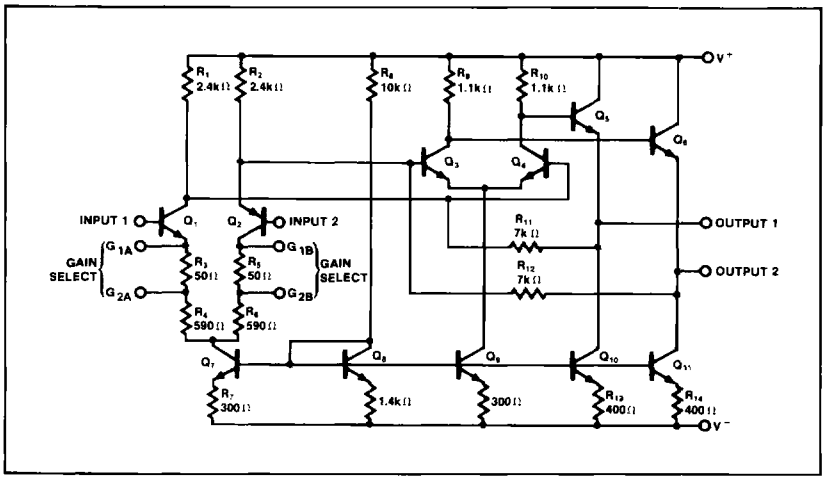


K PACKAGE



NOTE
Pin 5 connected to case.

CIRCUIT SCHEMATIC



ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNIT
Differential input Voltage	±5	V
Common mode input Voltage	±6	V
V_{CC}	±8	V
Ouput current	10	mA
Junction temperature	+150	°C
Storage temperature range	-65 to +150	°C
Operation temperature range		
μA733C	0 to +75	°C
μA733	-55 to +125	°C
P_D Power dissipation		
K package	500	mW
N, F package	670	mW

DC ELECTRICAL CHARACTERISTICS

T_A = +25°C, V_S = ±V, VCM = 0 unless otherwise specified.
Recommended operating supply voltages V_S = ±6.0V.

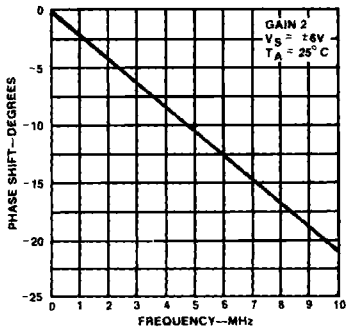
PARAMETER	TEST CONDITIONS	μA733C			μA733			UNITS
		Min	Typ	Max	Min	Typ	Max	
Differential voltage gain								
Gain 1[1]		250	400	600	300	400	500	V/V
Gain 2[2]	R_I = 2kΩ, V_{OUT} = 3Vp-p	80	100	120	90	100	110	V/V
Gain 3[3]		8.0	10	12	9.0	10	11	V/V
Bandwidth								
Gain 1[1]			40			40		MHz
Gain 2[2]			90			90		MHz
Gain 3[3]			120			120		MHz
Rise time								
Gain 1[1]			10.5			10.5		ns
Gain 2[2]	V_{OUT} = 1Vp-p		4.5	12		4.5	10	ns
Gain 3[3]			2.5			2.5		ns
Propagation delay								
Gain 1[1]			7.5			7.5		ns
Gain 2[2]	V_{OUT} = 1Vp-p		6.0	10		6.0	10	ns
Gain 3[3]			3.6			3.6		ns
Input resistance								
Gain 1[1]			4.0			4.0		kΩ
Gain 2[2]		10	30		20	30		kΩ
Gain 3[3]			250			250		kΩ
Input capacitance[2]	Gain 2		2.0			2.0		pF
Input offset current			0.4	5.0		0.4	3.0	μA
Input bias current			9.0	30		9.0	20	μA
Input noise voltage	BW = 1kHz to 10MHz		12			12		μVrms
Input voltage range		±1.0			±1.0			V
Common mode Rejection ratio								
Gain 2	VCM = ±V,f ≤ 100kHz	60	86		60	86		dB
Gain 2	VCM = ±1V,F = 5MHz		60			60		dB
Supply voltage Rejection ratio								
Gain 2	ΔV_S = ±0.5V	50	70		50	70		dB
Output offset voltage								
Gain 1[1]	R_L = ∞		0.6	1.5		0.6	1.5	V
Gain 2 and 3[2,3]			0.35	1.5		0.35	1.0	V
Output common mode voltage	R_L= ∞	2.4	2.9	3.4	2.4	2.9	3.4	V
Output voltage swing	R_L = 2k	3.0	4.0		3.0	4.0		
Output sink current		2.5	3.6		2.5	3.6		mA
Output resistance			20			20		Ω
Power supply current	R_L ± ∞		18	24		18	24	mA

NOTES

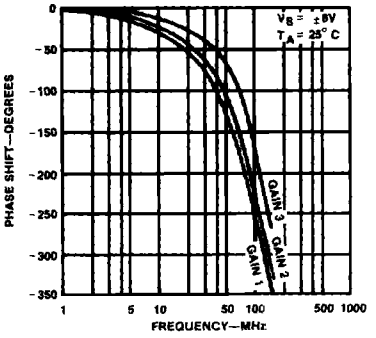
1. Gain select pins G_{1A} and G_{1B} connected together.
2. Gain select pins G_{2A} and G_{2B} connected together.
3. All gain select pins open.

TYPICAL PERFORMANCE CHARACTERISTICS

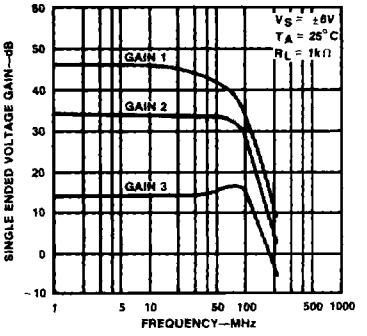
PHASE SHIFT AS A FUNCTION OF FREQUENCY



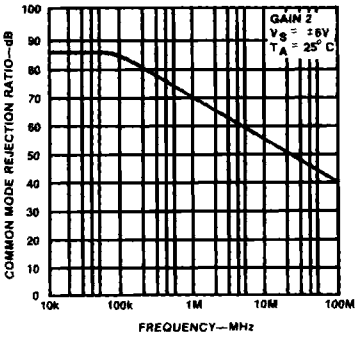
PHASE SHIFT AS A FUNCTION OF FREQUENCY



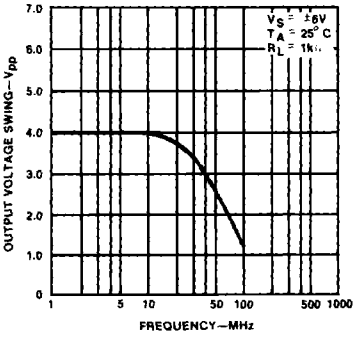
VOLTAGE GAIN AS A FUNCTION OF FREQUENCY



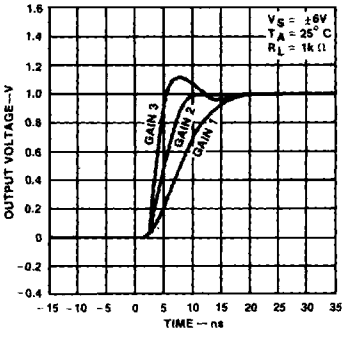
COMMON MODE REJECTION RATIO AS A FUNCTION OF FREQUENCY



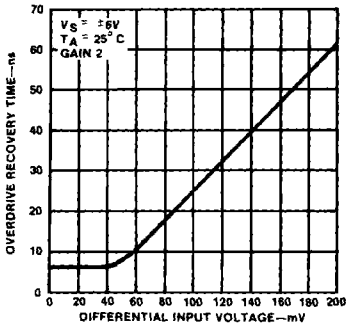
OUTPUT VOLTAGE SWING AS A FUNCTION OF FREQUENCY



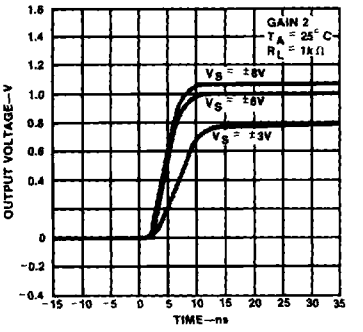
PULSE RESPONSE



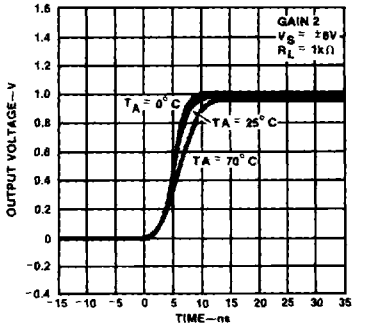
DIFFERENTIAL OVERDRIVE RECOVERY TIME



PULSE RESPONSE AS A FUNCTION OF SUPPLY VOLTAGE

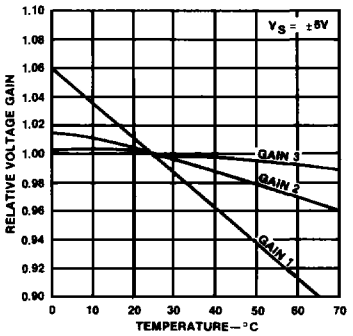


PULSE RESPONSE AS A FUNCTION OF TEMPERATURE

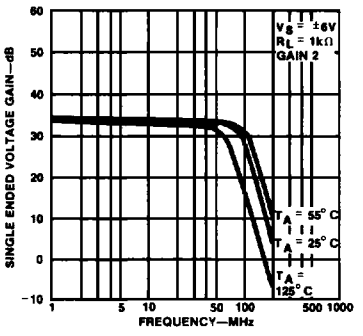


TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)

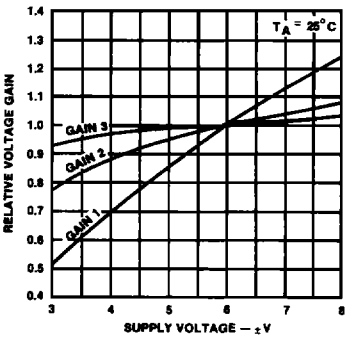
VOLTAGE GAIN AS A FUNCTION OF TEMPERATURE



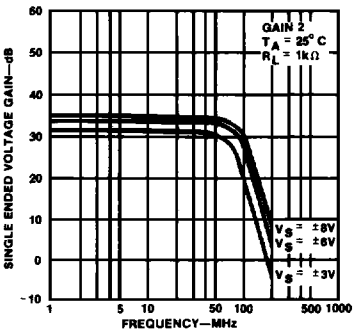
GAIN vs FREQUENCY AS A FUNCTION OF TEMPERATURE



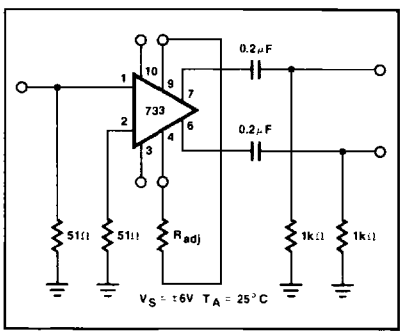
VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE



GAIN vs FREQUENCY AS A FUNCTION OF SUPPLY VOLTAGE

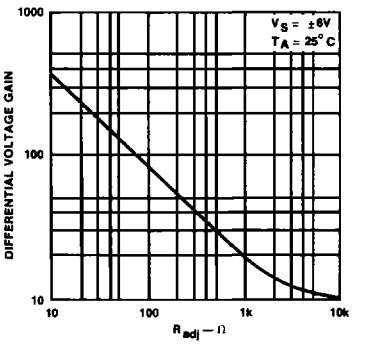


VOLTAGE GAIN ADJUST CIRCUIT

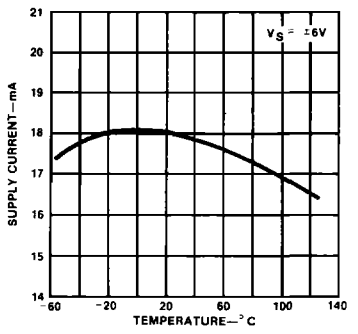


(Pin numbers apply to K Package)

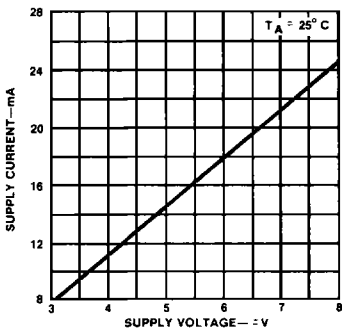
VOLTAGE GAIN AS A FUNCTION OF RADJ (FIGURE 3)



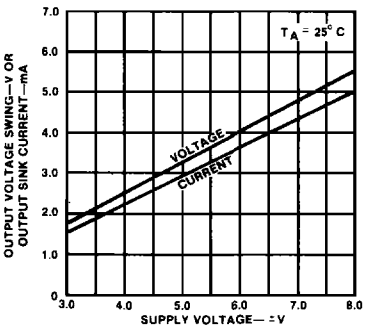
SUPPLY CURRENT AS A FUNCTION OF TEMPERATURE



SUPPLY CURRENT AS A FUNCTION OF SUPPLY VOLTAGE

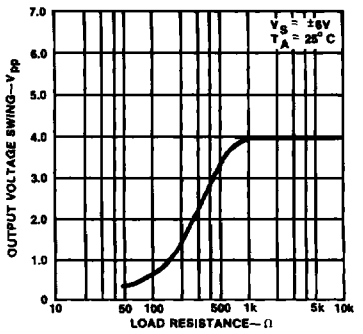


OUTPUT VOLTAGE AND CURRENT SWING AS A FUNCTION OF SUPPLY VOLTAGE

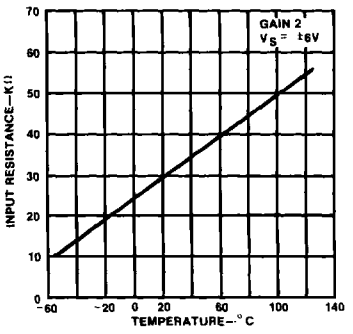


TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)

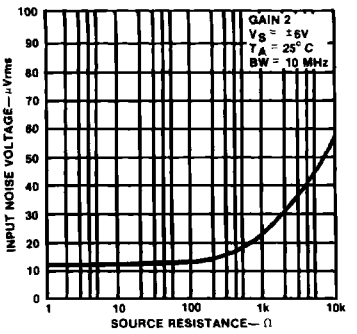
OUTPUT VOLTAGE SWING AS A FUNCTION OF LOAD RESISTANCE



INPUT RESISTANCE AS A FUNCTION OF TEMPERATURE



INPUT NOISE VOLTAGE AS A FUNCTION OF SOURCE RESISTANCE



TEST CIRCUITS T_A = 25°C unless otherwise specified.